



Faculty of Manufacturing Engineering

**SOL GEL PROCESS OF COBALT NANOPARTICLES
PREPARATION AS EFFECTIVE CATALYST FOR
CNT GROWTH PERFORMANCE**

NOR NAJIHAH BINTI ZULKAPLI

**MASTER OF SCIENCE IN MANUFACTURING
ENGINEERING**

2016



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NOR NAJIHAH BINTI ZULKAPLI

**A thesis submitted
In fulfilment of the requirements for the degree of Master of Science
In Manufacturing Engineering**

FACULTY OF MANUFACTURING ENGINEERING

UNIVERSITI TEKNIKAL MALAYSIA MELAKA

2016

DECLARATION

I declare that this thesis entitle “Sol Gel Process of Cobalt Nanoparticles Preparation as Effective Catalyst for CNT Growth Performance“ is the result of my own research except as cited in the references. The thesis has not been accepted for any degree and is not concurrently submitted in candidature of any other degree.

Signature :

Name :

Date :

APPROVAL

I hereby declare that I have read this thesis and my opinion this thesis is sufficient in terms of scope and quality for the award of Master of Science in Manufacturing Engineering (Advanced Materials).

Signature :

Supervisor Name :

Date :

DEDICATION

I dedicate this thesis to my family especially to my parents for their support and understanding throughout my master study. Next, I would like to dedicate this thesis to my friends, Raja Noor Amalina, Norasimah and Elyas for always give support for completing this project. Last but not least I would like to dedicate this thesis to my supervisor, Engr. Dr. Mohd Asyadi Azam, and co-supervisor, Prof. Madya. Dr. Mohd Warikh, for their advices and support all this time. Thank you so much.

ABSTRACT

Carbon nanotube (CNT) is a well known structure that has extraordinary properties and widely used in many application. The presence of metal catalyst is needed for CNT growth by CVD technique. The properties of as-grown CNT is depends on the properties of metal catalyst. The aim of this project was to produce cobalt (Co) catalyst by spin coating process for carbon nanotube (CNT) growth. It was targeting to study the catalyst thin film formation by using solution process, analyze the catalyst nanoparticles transformation from the deposited thin film and confirm the structural properties of as-grown CNT by Raman spectroscopy. This project was divided into two major parts. The first part was catalyst preparation and the second part was CNT growth. The Co catalyst was prepared by spin coating and heat treatment process. The spin speed of spin coating was varied from 6500 rpm to 8000 rpm with 500 rpm interval and spinning duration of 60 s. The post-heat treatment temperature was varied from 450 °C to 600 °C with interval of 50 °C and heating duration of 10 minutes. The Co catalyst nanoparticles formed after heat treatment process then being used for CNT growth by alcohol catalytic CVD (ACCVD) technique. The CVD processing temperature was varied in range of 650-750 °C with 25 °C interval. The CVD processing time was fixed for 15 minutes. The Co catalyst and its nanoparticles were characterized by field emission scanning electron microscopy (FESEM), X-ray diffraction (XRD) and X-ray photoelectron spectroscopy (XPS) while the structural properties of the as-grown CNT was studied by Raman spectroscopy. The thickness of Co catalyst thin film was decreasing by the increasing of spin speed. Based on four varied value of spin speed; 6500, 7000, 7500 and 8000 rpm, the optimum spin speed with smallest thickness of Co catalyst thin film, 12.1 nm, was at 8000 rpm. Besides, the average size of Co nanoparticle was increased by the increasing of post-heat treatment temperature. The optimum temperature was found at 450 °C with 10.64 nm average size of Co nanoparticles. The Co catalyst thin film was confirmed by XRD and XPS analysis to have CoO compound structure while the Co catalyst nanoparticles was in Co_3O_4 structure. Then, 700 °C was found to be the optimum CVD processing temperature for the CNT grown on spin coated Co catalyst nanoparticles with the highest I_G/I_D ratio of 6.398. Additionally, the presence of SWCNT structure was confirmed by the presence of RBM peak in range of 100-400 cm^{-1} Raman shift measured by Raman spectroscopy. The measured SWCNT tube diameters were less than 1.5 nm. Hence, it can be concluded that the thickness of Co catalyst thin film can be controlled by controlling the spin speed of spin coating. Optimum post-heat and CVD processing temperature is crucial for Co catalyst nanoparticles formation and obtaining good quality of CNT. The as-grown CNT in this project has high potential in electronic device application due to the smaller SWCNT tube diameter and good quality.

ABSTRAK

Tiub nano karbon (CNT) adalah sebuah struktur terkenal yang mempunyai ciri-ciri yang luar biasa dan digunakan secara meluas dalam pelbagai aplikasi. Kehadiran pemangkin logam diperlukan untuk penghasilan CNT melalui teknik CVD. Sifat-sifat CNT yang terhasil bergantung kepada sifat-sifat pemangkin logam yang digunakan. Tujuan projek ini adalah untuk menghasilkan kobalt (Co) pemangkin melalui proses salutan putaran untuk penghasilan CNT. Ia menyasarkan untuk mengkaji pembentukan filem pemangkin yang nipis dengan menggunakan solution process, menganalisis transformasi filem pemangkin yang nipis tersebut kepada bentuk nanopartikel dan mengesahkan sifat-sifat struktur CNT yang terhasil dengan menggunakan Raman spektroskopi. Projek ini telah dibahagikan kepada dua bahagian utama. Bahagian pertama adalah penghasilan pemangkin dan bahagian kedua adalah penghasilan CNT. Co Pemangkin telah dihasilkan melalui proses salutan putaran dan proses rawatan haba. Kelajuan putaran salutan putaran telah dimanipulasikan dari 6500 rpm ke 8000 rpm dengan selang 500 rpm dan tempoh berputar 60 s. Suhu rawatan selepas haba telah dimanipulasikan dari 450 °C 600 °C dengan selang 50 °C dengan tempoh pemanasan selama 10 minit. Nanopartikel pemangkin yang terbentuk selepas melalui proses rawatan haba kemudiannya digunakan untuk penghasilan CNT dengan teknik alkohol pemangkin CVD (ACCVD). Suhu pemprosesan CVD telah dimanipulasikan dalam lingkungan 650-750 °C dengan selang 25 °C. Masa pemprosesan CVD telah ditetapkan selama 15 minit. Bersama pemangkin dan nanopartikel yang telah dianalisis oleh pelepasan bidang mikroskop imbasan elektron (FESEM), sinar-X pembelauan (XRD) dan sinar-X fotoelektron spektroskopi (XPS) manakala sifat-sifat struktur yang CNT yang terhasil telah dikaji dengan spektroskopi Raman. Ketebalan Co pemangkin filem nipis telah berkurangan dengan peningkatan kelajuan putaran. Berdasarkan empat nilai yang dimanipulasikan daripada kelajuan putaran; 6500, 7000, 7500 dan 8000 rpm, kelajuan putaran optimum dengan ketebalan terkecil pemangkin Co filem nipis, 12.1 nm, adalah pada 8000 rpm. Selain itu, saiz purata Co nanopartikel telah meningkat dengan peningkatan suhu rawatan selepas haba. Suhu optimum adalah pada 450 °C dengan 10.64 saiz purata nm Co nanopartikel. Filem pemangkin yang nipis tersebut telah disahkan oleh XRD dan XPS analisis mempunyai struktur CoO kompaun manakala Co nanopartikel pemangkin adalah dalam struktur Co₃O₄. Kemudian, 700 °C didapati sebagai suhu optimum pemprosesan CVD bagi CNT yang terhasil daripada Co nanopartikel dengan nisbah I_G/I_D tertinggi iaitu 6.398. Selain itu, kehadiran struktur single-walled CNT (SWCNT) disahkan dengan kehadiran puncak RBM dalam julat 100-400 cm⁻¹ yang diukur dengan spektroskopi Raman. Diameter tiub SWCNT yang diukur adalah kurang daripada 1.5 nm. Kesimpulannya, ketebalan Co filem pemangkin yang nipis boleh dikawal dengan mengawal kelajuan putaran salutan putaran. CNT yang terhasil dalam projek ini berpotensi tinggi dalam aplikasi peranti elektronik kerana mempunyai diameter tiub SWCNT yang lebih kecil dan kualiti yang baik.

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LIST OF ABBREVIATIONS

CNT	Carbon Nanotube
VA-CNT	Vertically aligned carbon nanotube
HA-CNT	Horizontally aligned carbon nanotube
SWCNT	Single-walled carbon nanotube
MWCNT	Multi-walled carbon nanotube
CVD	Chemical vapour deposition
ACCVD	Alcohol catalytic chemical vapour deposition
WACVD	Water-assisted chemical vapour deposition
PECVD	Plasma-enhanced chemical vapour deposition
FCCVD	Floating catalyst chemical vapour deposition
TCVD	Thermal chemical vapour deposition
PVD	Physical vapour deposition
Co	Cobalt
FESEM	Field emission scanning electron microscopy
XRD	X-ray diffraction
XPS	X-ray photoelectron spectroscopy
TEM	Transmission electron microscopy
HR-TEM	High resolution transmission electron microscopy
Si	Silicon
BE	Binding energy
I_G/I_D	G-band intensity over D-band intensity
RBM	Radial breathing mode

LIST OF PUBLICATIONS

(i) Peer Reviewed Journals

1. **Zulkapli, N. N.**, Azam, M. A., Zubir, N. M. A. M., Ithnin, N. A. and Rashid, M. W. A., 2015. A Simple and Room Temperature Sol-gel Process for the Fabrication of Cobalt Nanoparticles as an Effective Catalyst for Carbon Nanotube Growth. *RSC Advances*, 5(116), pp.95872-95881.
2. **Zulkapli, N. N.**, Ithnin, N. A., Azren, N. M. and Azam, M. A., 2015. Raman Spectra Analysis of Single-walled Carbon Nanotube Grown from Spin-coated Cobalt Catalyst at Different Temperatures. *Journal of Engineering and Applied Sciences*, 11(3), pp.1550-1554.
3. **Zulkapli, N.N.**, Manaf, M. E. A., Maulod, H. E. A., Abdul Manaf, N. S., Raja Seman, R. N. A., Bistamam, M. S. A., Talib, E. and Azam, M. A., 2015. Control of Cobalt Catalyst Thin Film Thickness by Varying Spin Speed in Spin Coating towards Carbon Nanotube Growth. *Applied Mechanics and Materials*, 761, pp.421–425.
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5. Azam, M. A., Nawi, Z. M., Azren, N. M. and **Zulkapli, N. N.**, 2015. Synthesis of Fe-Catalyst Nanoparticles by Solution Process towards Carbon Nanotube Growth. *Materials Technology: Advanced Performance Materials*, 30(A1), pp. A8-A13.

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7. Talib, E., Lau, K. –T., Zaimi, M., Bistamam, M. S. A., Abdul Manaf, N. S., Raja Seman, R. N. A., **Zulkapli, N. N.** and Azam, M. A., 2015. Electrochemical Performance of Multi Walled Carbon Nanotube and Graphene Composite Films Using Electrophoretic Deposition Technique. *Applied Mechanics and Materials*, 761, pp.468–472.
8. Azam, M. A., Hassan, A., Mohamad, N., Talib, E., Abdul Manaf, N. S., **Zulkapli, N. N.**, Raja Seman, R. N. A. and Bistamam, M. S. A., 2015. Fabrication of Activated Carbon Filled Epoxidized Natural Rubber Composite Using Solvent Casting Method. *Applied Mechanics and Materials*, 761, pp. 426-430

(ii) Conferences

1. International Symposium on Functional Materials (ISFM) 2014 (Poster), Singapore, 4-7th Aug 2014
 - Title : Synthesis of Cobalt Catalyst Nanoparticles by Solution Process for Carbon Nanotube Growth

2. International Symposium on Advanced Functional Materials (ISAFM) 2014 (Oral), Kuala Lumpur, 1-2th Aug 2014
 - Title : Synthesis of Fe-Catalyst Nanoparticles by Solution Process towards CNT Growth

3. International Design and Concurrent Engineering (iDECON) 2014 (Oral), Avillion Legacy Hotel, Melaka, 22-23rd Sept 2014
 - Title : Control of Cobalt Catalyst Thin Film Thickness by Varying Spin Speed in Spin Coating towards Carbon Nanotube Growth

4. Malaysian Technical Universities Conference on Engineering and Technology (MUCET) 2015 (Oral), KSL Resort Hotel, Johor Bahru, 11-13th October 2015
 - Title: Raman Spectra Analysis of Single-Walled Carbon Nanotube Grown from Spin-Coated Cobalt Catalyst at Different Temperatures

CHAPTER 1

INTRODUCTION

1.0 Background

This is the beginning of thesis content. In this chapter, it consists of four parts. The first part is the introduction of the carbon nanotube (CNT), its structure, the growth and the importance of catalyst in CNT growth. Then, it is followed by the problem statement of the project, objectives and closed with scopes of this project.

1.1 Introduction

Global industries have been shifted from micro technology to nanotechnology. Nanotechnology is a technology that has been spread into many fields of studies such as sciences, engineering, medicine and many more. The expended technology is all about producing and manipulating small objects as well as building from extremely small objects which is less than 100 nm. By making things smaller, it gives merit to the economic and technology such as cut-off the production cost by a mass production of products. This is due to only small quantity of the extraordinary properties of nanomaterials is needed in a particular production. Thus, the shortage of nature sources can be solved respectively.

CNT is the example of nanomaterial that has been widely used in many fields of application. It was being used in electronic device, energy storage device and also being used as a reinforcement material in composite. CNT is just a tiny structure in nano-scales in which the diameter approximately 10,000 times smaller than human hair but yet it can

give huge impact on science and technology. Ever since the existence of this material has been exposed by Sumio Iijima in 1991 and acknowledged by the researchers (Bethune et al., 1993; Yacaman et al., 1993; Amelinckx et al., 1994; Ivanov et al., 1994; Thess et al., 1996; Hernadi et al., 2000; Ermakova and Ermakov, 2002) due to the unique structure as well as the extraordinary properties; such as high electrical conductivity and good electronic properties in work function and the contact resistance with metals, it has been an interesting subject to be explored up till this century (Iijima, 1991; Hu et al., 2009).

According to Harris (2009), CNT is a structure formed from a repeated chemical element of carbon (C) in which bonded by covalent bonding. Covalent bonding is a strong chemical bond that involves in sharing electron pairs between atoms. The three famous allotropes of carbon are 2D-graphite, 3D-diamond and amorphous carbon. The most well-known application of graphite was as cores in pencils. It has been used after lead due to the poisonous issue on lead back then. The second allotrope which is usually used along with the ring is the most favoured by women and also quite expensive. It is also the hardest nature material due to its diamond lattice arrangement. The highest hardness own by this structure leads to the restructured as synthetic diamond that being used as cutting and polishing tools in industries. Another form of carbon was discovered by Kroto is 0D-fullerence (Kroto, 2001). Due to that finding, nanotubes can be classified as one of the fullerence's family member.

CNT can be classified according to its growth alignment and helicity. There are two types of CNT based on growth alignment; 1) entangled CNT and 2) aligned CNT. Entangled CNT is the CNT that grown in random alignment. Aligned CNT is the CNT that grown either in vertical or horizontal alignment. The most favoured CNT based on the

growth direction for electronic devices is vertically aligned CNT (VA-CNT) instead of horizontally aligned CNT (HA-CNT) because it can improve the device capacitance performance (Yuan et al., 2008; Murakami et al., 2004; Huang et al., 2003). Moreover, for the CNT classified by the helicity, there are single-walled CNT (SWCNT) and multi-walled CNT (MWCNT) (Azam et al., 2011). As illustrated in Figure 1.1, the basic structure for both types of CNT is 2D-graphene sheet. SWCNT can be obtained by wrapping a 2D-graphene sheet into a seamless cylindrical structure or by elongating a Bulkyball or C_{60} to be a tubular structure, (Harris, 2009; Azam et al., 2013; Iijima and Ichihashi, 1993; Bethune et al., 1993).

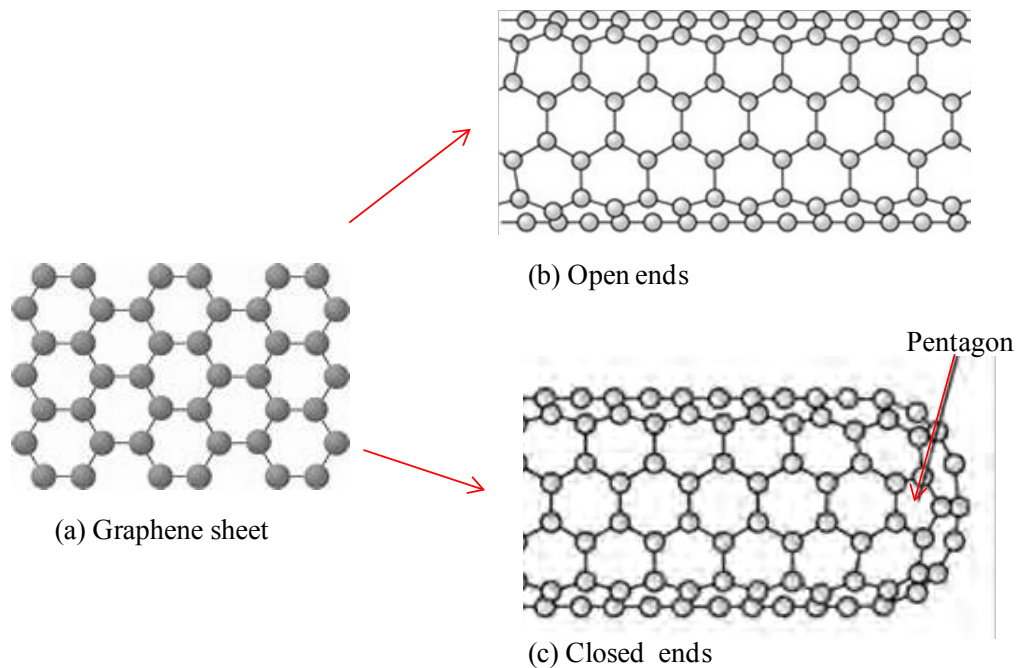


Figure 1.1: Basic structure of carbon nanotube; (a) graphene sheet, (b) cylindrical shape with open ends and (c) cylindrical shape with closed ends (Hawk's Perch Technical Writing, 2014)

The graphene sheet can be wrapped by three orientations; 1) zigzag, 2) armchair and 3) chiral (Harris, 2009; Liu et al., 2013). The different wrapping orientation as illustrated in Figure 1.2 gives different electrical property in which can be employed in